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## NTE1722 Integrated Circuit Pulse Width Modulator (PWM) Control Circuit

**Description:**

The NTE1722 is a high performance pulse width modulator integrated circuit in an 18-Lead DIP type package intended for fixed frequency switching regulators and other power control applications.

Functions included in this IC are a temperature compensated voltage reference, sawtooth oscillator, error amplifier, pulse width modulator, pulse metering and steering logic, and two high current totem pole outputs ideally suited for driving the capacitance of power FETs at high speeds.

Additional protective features include soft start and undervoltage lockout, digital current limiting, double pulse inhibit, adjustable dead time and a data latch for single pulse metering. All digital control ports are TTL and B-series CMOS compatible. Active low logic design allows easy wired-OR connections for maximum flexibility. The versatility of this device enables implementation in single-ended or push-pull switching regulators that are transformerless or transformer coupled.

**Features:**

- 8.0 to 35 Volt Operation
- 5.0 Volt  $\pm 1\%$  Trimmed Reference
- 1.0Hz to 400kHz Oscillator Range
- Dual Source/Sink Current Outputs:  $\pm 100\text{mA}$
- Digital Current Limiting
- Programmable Dead Time
- Wide Current Limit Common Mode Range
- Guaranteed 6 Unit Synchronization

**Absolute Maximum Ratings:** (Values beyond which damage may occur)

Supply Voltage, $V_{CC}$ .....	+40V
Collector Supply Voltage, $V_C$ .....	+40V
Logic Inputs .....	-0.3 to +5.5V
Analog Inputs .....	-0.3 to $V_{CC}$ V
Output Current (Source or Sink), $I_O$ .....	$\pm 200\text{mA}$
Reference Load Current ( $V_{CC} = 40\text{V}$ , Note 1), $I_{ref}$ .....	50mA
Logic Sink Current .....	15mA
Power Dissipation ( $T_A = +25^\circ\text{C}$ ), $P_D$ .....	1000mW
Derate Above $50^\circ\text{C}$ .....	10mW/ $^\circ\text{C}$
Power Dissipation ( $T_C = +25^\circ\text{C}$ ), $P_D$ .....	3000mW
Derate Above $25^\circ\text{C}$ .....	24mW/ $^\circ\text{C}$
Operating Junction Temperature, $T_J$ .....	+ 150 $^\circ\text{C}$
Storage Temperature Range, $T_{stg}$ .....	-65 $^\circ$ to +150 $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient, $R_{thJA}$ .....	100 $^\circ\text{C}/\text{W}$
Lead Temperature (During Soldering, 10sec), $T_L$ .....	$\pm 300^\circ\text{C}$

Note 1. Maximum junction temperature must be observed.

**Recommended Operating Conditions:**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage	$V_{CC}$		+8.0	–	+35	V
Collector Supply Voltage	$V_C$		+4.5	–	+35	V
Output Sink/Source Current (Each Output)	$I_O$		0	–	$\pm 100$	mA
Reference Load Current	$I_{ref}$		0	–	20	mA
Oscillator Frequency Range	$I_{ref}$		0	–	20	mA
Oscillator Timing Resistor	$R_T$		2.0	–	150	k $\Omega$
Oscillator Timing Capacitor	$C_T$		0.001	–	20	$\mu$ F
Available Deadtime Range (40kHz)	–		3.0	–	50	%
Operating Junction Temperature Range	$T_J$		0	–	+125	$^{\circ}$ C

**Electrical Characteristics:** ( $V_{CC} = 15V$ ,  $T_J = 0^{\circ}$  to  $+125^{\circ}$ C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Referend Section</b> ( $I_L = 0mA$ unless otherwise specified)						
Reference Output Voltage	$V_{ref}$	$T_J = +25^{\circ}$ C	4.90	5.00	5.10	V
Line Regulation	$Reg_{line}$	$+8.0V \leq V_{CC} \leq +35V$	–	10	30	mV
Load Regulation	$Reg_{load}$	$0mA \leq I_L \leq 20mA$	–	10	50	mV
Temperature Stability	$\Delta V_{ref}/\Delta T_J$		–	10	–	mV
Total Reference Output Voltage Variation	$\Delta V_{ref}$	$+8.0V \leq V_{CC} \leq +35V$ , $0mA \leq I_L \leq 20mA$	4.85	5.00	5.15	V
Short Circuit Current	$I_{SC}$	$V_{ref} = 0V$ , Note 1	25	80	125	mA
<b>Undervoltage Lockout</b>						
Reset Output Voltage	–	$V_{ref} = +3.8V$	–	0.2	0.4	V
		$V_{ref} = +4.8V$	2.4	4.8	–	V
<b>Oscillator Section</b> (Note 2)						
Initial Accuracy	–	$T_J = +25^{\circ}$ C	–	$\pm 3.0$	$\pm 8.0$	%
Frequency Stability over Power Supply Range	$\frac{\Delta f_{osc}}{\Delta V_{CC}}$	$+8.0V \leq V_{CC} \leq +35V$	–	0.5	1.0	%
Frequency Stability over Temperature	$\frac{\Delta f_{osc}}{\Delta T_J}$	$\Delta T_J = 0^{\circ}$ to $+125^{\circ}$ C	–	2.0	–	%
Minimum Frequency	$f_{min}$	$R_T = 150k\Omega$ , $C_T = 20\mu F$	–	0.5	–	Hz
Maximum Frequency	$f_{max}$	$R_T = 2k\Omega$ , $C_T = 0.001\mu F$	400	–	–	kHz
Sawtooth Peak Voltage	$V_{osc(p)}$	$V_{CC} = +35V$	–	3.0	3.5	V
Sawtooth Valley Voltage	$V_{osc(v)}$	$V_{CC} = +8V$	0.45	0.8	–	V
<b>Error Amplifier Section</b> ( $0V \leq V_{CM} \leq +5.2V$ unless otherwise specified)						
Input Offset Voltage	$V_{IO}$	$R_S \leq 2k\Omega$	–	20	10	mV
Input Bias Current	$I_{IB}$		–	–350	–2000	nA
Input Offset Current	$I_{IO}$		–	35	200	nA
DC Open Loop Gain	$A_{VOL}$	$R_L \geq 10M\Omega$	60	72	–	dB

Note 1. Maximum junction temperature must be observed.

Note 2.  $f_{OSC} = 40kHz$  ( $R_T = 4.12k\Omega \pm 1\%$ ,  $C_T = 0.01\mu F \pm 1\%$ ,  $R_D = 0\Omega$ )

**Electrical Characteristics (Cont'd):** ( $V_{CC} = 15V$ ,  $T_J = 0^\circ$  to  $+125^\circ C$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Error Amplifier Section (Cont'd)</b> ( $0V \leq V_{CM} \leq +5.2V$ unless otherwise specified)						
High Output Voltage	$V_{OH}$	$V_{Pin1} - V_{Pin2} \geq +150mV$ , $I_{Source} = 100\mu A$	3.6	4.2	–	V
Low Output Voltage	$V_{OL}$	$V_{Pin2} - V_{Pin1} \geq +150mV$ , $I_{Sink} = 100\mu A$	–	0.2	0.4	V
Common Mode Rejection Ratio	CMRR	$R_S \leq 2k\Omega$	70	94	–	dB
Power Supply Rejection Ratio	PSRR	$+12V \leq V_{CC} \leq +18V$	66	80	–	dB
<b>PWM Comparator Section</b> (Note 2)						
Minimum Duty Cycle	$DC_{min}$	$V_{compensation} = +0.4V$	–	–	0	%
Maximum Duty Cycle	$DC_{max}$	$V_{compensation} = +3.6V$	45	49	–	%
<b>Digital Ports</b> (SYNC, SHUTDOWN, RESET)						
Output Voltage, High Logic Level	$V_{OH}$	$I_{source} = 40\mu A$	2.4	4.0	–	V
Output Voltage, Low Logic Level	$V_{OL}$	$I_{sink} = 3.6mA$	–	0.2	0.4	V
Input Current, High Logic Level	$I_{IH}$	$V_{IH} = +2.4V$	–	–125	–200	$\mu A$
Input Current, Low Logic Level	$I_{IL}$	$V_{IL} = +0.4V$	–	–225	–360	$\mu A$
<b>Current Limit Comparator Section</b> ( $0V \leq V_{CM} \leq +12V$ unless otherwise specified)						
Sense Voltage	$V_{sense}$	$R_S \leq 50\Omega$	80	100	120	mV
Input Bias Current	$I_{IB}$		–	–3	–10	$\mu A$
<b>Soft-Start Section</b>						
Error Clamp Voltage		Reset = +0.4V	–	0.1	0.4	V
$C_{Soft-Start}$ Charging Current	$I_{CS}$	Reset = +2.4V	50	100	150	$\mu A$
<b>Output Drivers</b> (Each Output, $V_C = +15Vdc$ unless otherwise specified)						
Output High Level	$V_{OH}$	$I_{source} = 20mA$	12.5	13.5	–	V
		$I_{source} = 100mA$	12.0	13.0	–	V
Output Low Level	$V_{OL}$	$I_{Sink} = 20mA$	–	0.2	0.3	V
		$I_{Sink} = 100mA$	–	1.2	2.0	V
Collector Leakage	$I_{C(Leak)}$	$V_C = +40V$	–	50	150	$\mu A$
Rise Time	$t_r$	$C_L = 1000pF$	–	0.3	0.6	$\mu s$
Fall Time	$t_f$		–	0.1	0.2	$\mu s$
Supply Current	$I_{CC}$	Shutdown + +0.4V, $V_{CC} = +35V$ , $R_T = 4.12k\Omega$	–	18	30	mA

Note 2.  $f_{OSC} = 40kHz$  ( $R_T = 4.12k\Omega \pm 1\%$ ,  $C_T = 0.01\mu F \pm 1\%$ ,  $R_D = 0\Omega$ )

### Pin Connection Diagram

